

Coulomb Gaps in a Strong Magnetic Field

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Abstract

We report on a study of interaction effects in the tunneling density-of-states of a disordered two-dimensional electron gas in the strong magnetic field limit where only the lowest Landau level is occupied. Interactions in the presence of disorder are accounted for by performing finite-size self-consistent Hartree-Fock calculations. We find evidence for the formation of a pseudo-gap with a tunneling density-of-states which vanishes at the Fermi energy.

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In the absence of a magnetic field, interaction effects in disordered electronic systems cause dramatic reductions in the tunneling density-of-states (DOS), $g_T(\epsilon)$, at energies near the chemical potential μ . In two-dimensions in the weak disorder limit the relative suppression of $g_T(\mu)$ increases logarithmically with decreasing temperature [1,2]. At sufficiently low temperatures, where the weak-disorder approximation fails, all states are localized. For localization lengths small compared to the distance between electrons (the classical limit) the Coulomb gap theory of Efros and Shklovskii [3] is expected [4] to apply. In the strong magnetic field limit, the one-body electronic spectrum in the absence of interactions and disorder consists of macroscopically degenerate Landau levels and the behavior of $g_T(\epsilon)$ promises to be even richer. Weak-disorder theory gives [5] the same temperature dependence as at $B = 0$, although because of the absence of a small parameter it cannot be formally justified even at high temperatures. At very low temperatures all states in disordered samples are expected to be localized except at a single energy within each Landau level and Polyakov and Shklovskii [7] have recently argued that the low-temperature transport properties [6] of disordered samples in strong magnetic fields provide indirect evidence for Coulomb gap formation. Direct experimental evidence of strong suppression of $g_T(\epsilon)$ for ϵ near μ comes from the recent experiments of Ashoori [8] *et al.* and Eisenstein [9] *et al.* In this Letter we report on the first study of the suppression of $g_T(\epsilon)$ in a disordered two dimensional gas of quantum electrons at strong magnetic fields.

We restrict our attention here to the strong magnetic field limit where the Landau level filling factor, $\nu \equiv N/N_\phi < 1$, the electrons are completely spin-polarized, and Landau level mixing by interactions or disorder can be neglected. (Here $N_\phi = BL_xL_y/\Phi_0 \equiv L_xL_y/(2\pi\ell^2)$ is the number of states per Landau level, $\Phi_0 = hc/e$ is the magnetic flux quantum and N the number of electrons.) Coulomb interactions are treated self-consistently within the Hartree-Fock approximation (HFA). As we discuss further below the HFA becomes exact in the classical limit of strongly localized states and is generally expected to be accurate when the disorder energy scale is larger than the interaction energy scale. Calculations have been completed for $\nu = 1/5$ and for $\nu = 1/2$. In the former case the states near the Fermi level

in the absence of interactions have a localization length comparable to the distance between electrons and we find clear evidence of the formation of a pseudogap where the DOS at the Fermi level vanishes in the thermodynamic limit. As far as we are aware ours are the first calculations which demonstrate the occurrence of a Coulomb gap away from the classical limit. We should expect to find qualitatively similar results at other values of ν , except possibly at $\nu = 1/2$ (see below).

We perform our calculations in the Landau gauge ($\vec{A} = (0, Bx, 0)$) and apply quasiperiodic boundary conditions to the HF single-particle orbitals inside a rectangle with sides L_x and L_y . The basis states used to represent the HF Hamiltonian are related to elliptic theta functions and can be labeled by a set of guiding centers $|X_i\rangle$, $i = 1, \dots, N_\phi$ inside the fundamental cell of the finite-size system [10]. The finite-size system HF calculations in the absence of disorder have been described in detail previously [11]. An important simplification related to the strong magnetic field limit [12] is the fact that both Hartree and Fock potentials can be expressed as a functional of the electron density:

$$\langle X_j | V_{HF} | X_i \rangle = \sum_{\vec{q}} \Delta(\vec{q}) \exp \left[\frac{iq_x(X_i + X_j)}{2} \right] \delta(j, i + m_y) U_{HF}(\vec{q}) \quad (1)$$

Here the sum over $\vec{q}$ is over the discrete set of wavevectors consistent with the boundary conditions and $\delta(n', n)$ is 1 if $n' = n \pmod{N_\phi}$ and 0 otherwise. The quantity $\Delta(\vec{q})$ is proportional [11] to the Fourier component of the charge density at wavevector $\vec{q}$ and is calculated from the eigenvectors of the HF Hamiltonian by

$$\Delta(\vec{q}) = \frac{1}{N_\phi} \sum_{j=1}^{N_\phi} \sum_{j'=1}^{N_\phi} \delta(j', j + m_y) \exp \left[\frac{-iq_x(X_j + X_{j'})}{2} \right] \sum_{\alpha=1}^N \langle X_{j'} | \alpha \rangle \langle \alpha | X_j \rangle. \quad (2)$$

In Eq. (2) the sum over α is over the N lowest energy eigenvectors of the HF Hamiltonian. $U_{HF}(\vec{q})$ includes both Coulomb and exchange interactions and needs to be evaluated [11] only once for each finite system size. $U_{HF}(\vec{q})$ is proportional to $e^2/\kappa\ell$ (κ is the dielectric constant) which is the characteristic interaction energy scale for interacting electrons in the lowest Landau level.

We have used a model disorder potential consisting of N_I δ -function scatterers with

strength uniformly distributed between $-\lambda$ and λ and scattering centers uniformly distributed inside the fundamental cell of the finite-size system. The disorder-averaged DOS in the absence of interactions is known exactly for this model [13] and similar models have been used previously to study localization of non-interacting electrons in strong magnetic fields [14]. For a given disorder realization the eigenstates $|\alpha\rangle$ and eigenvalues ε_α of the HFA satisfy the following equation:

$$\sum_i \langle X_j | H_{HF} | X_i \rangle \langle X_i | \alpha \rangle \equiv \sum_i \left[\langle X_j | V_I | X_i \rangle + \langle X_j | V_{HF} | X_i \rangle \right] \langle X_i | \alpha \rangle = \varepsilon_\alpha \langle X_j | \alpha \rangle. \quad (3)$$

For each disorder realization Eqs. (3), (1), and (2) were solved by iterating to self-consistently for six different values $\gamma \equiv (e^2/\kappa\ell)/\Gamma$ where $\Gamma = (\lambda^2 N_I / \ell^2 L_x L_y)^{1/2}$ is the characteristic disorder potential energy scale. (For this model the self-consistent Born approximation DOS is non-zero for $|\epsilon| < (2/3\pi)^{1/2} \Gamma \sim 0.46\Gamma$.) The HF equations were solved first at $\gamma = 0$ where no self-consistency is required, and then at $\gamma = \gamma_i \equiv 0.1i$, $i = 1, \dots, 5$. For $\gamma = \gamma_i$ the iteration is started using the self-consistent charge density obtained at $\gamma = \gamma_{i-1}$. The average change in the charge-density Fourier components at iteration j , $[\sum_{\vec{q}} |\Delta_{j+1}(\vec{q}) - \Delta_j(\vec{q})|] N_\phi^{-2} \equiv \delta$, was evaluated to test for convergence. The calculations were considered to be converged once $\delta < 10^{-6}$. All the numerical results reported below were obtained for $N_I = 5N_\phi$. Square ($L_x = L_y = L$) systems of various sizes were considered for both $\nu = 1/5$ and $\nu = 1/2$.

For ν or $1 - \nu$ very small the classical limit is approached. In this limit the HF energy for the orbital at disorder site i is

$$E_i = \phi_i + \sum_j [\langle ij | V | ij \rangle - \sum_j \langle ij | V | ji \rangle] f_j \quad (4)$$

where ϕ_i and f_i are the disorder-potential energy at site i and the occupation number at site i . If the overlap between different orbitals can be neglected the exchange matrix element in Eq. (4) is zero unless $i = j$ and we obtain $E_i = \phi_i + \sum_{j \neq i} V_{ij} f_j$ where $V_{ij} = \langle ij | V | ij \rangle$. In the localized limit the only effect of exchange is to cancel the self-interaction energy of each orbital. This is just the classical expression for the energy of an electron at site i used in

previous investigations of the Efros-Shklovskii Coulomb gap [4]. Thus the HF approximation captures all the physics of the classical limit but is able to include quantum effects without additional difficulty.

Typical numerical results are shown in Fig. (1) for $\nu = 1/5$ and in Fig. (2) for $\nu = 1/2$. In the HFA the tunneling DOS is given by the spectral density of HF eigenvalues. We plot the total number of eigenvalues which occur in a range of width ΔE around the energy E , $D_{\Delta E}(E)$, for all disorder realization studied. (Note that the histogram box widths used to obtain these results are several times larger than the typical energy level spacing at the Fermi energy.) For a given system size the DOS exhibits a minimum which is tied to the Fermi level and which deepens and broadens as the interaction strength increases or as the disorder decreases. For a given ratio of interaction strength to disorder the DOS minimum becomes more pronounced as the system size increases.

In the classical limit the difference between the energy of an orbital which is occupied and an orbital which is empty must exceed [3,4] the excitonic energy associated with the transfer of an electron from the occupied site to the empty site. For a finite size square system with periodic boundary conditions the minimum possible excitonic energy (and hence the minimum possible level spacing) occurs when the displacement of the charge is $(L, L)/\sqrt{2}$ and equals $\sim 2.285e^2/\kappa L$. This energy provides a lower bound on the energy-level-spacing at the Fermi level in a disordered system of classical electrons. In the thermodynamic limit Efros and Shklovskii have estimated that for classical electrons the impurity-averaged DOS at the Fermi level in two-dimensions vanishes linearly with a coefficient which corresponds to an energy level spacing at the Fermi level of $\sqrt{2\pi}e^2/\kappa L \sim 2.507e^2/\kappa L$. The dependence of our HF spectrum DOS minimum on system size is illustrated in Fig. (3) where we plot the DOS per Landau Level at the Fermi energy as a function of $x \equiv (\Gamma/N_\phi)/(e^2/\kappa L)$. x is proportional to the ratio of the energy-level-spacing in a finite system of electrons without interactions to the energy-level-spacing at the Fermi level for a disordered system of classical electrons with Coulomb interactions. We see from Fig. (3) that to a good approximation the Fermi level DOS depends only on this ratio. For large x Coulomb interactions are

unimportant and $g_T(\epsilon_F)$ approaches the known result for non-interacting electrons, even for quite small system sizes. For small x the numerical results suggest that $g_T(\epsilon_F)$ is proportional to x with a slope corresponding to an energy-level spacing at the Fermi level of $\sim 0.8e^2/\kappa L$ for $\nu = 1/5$ and $\sim 0.6e^2/\kappa L$ for $\nu = 1/2$. This decrease in coefficient of the L^{-1} energy-level-spacing at the Fermi level for large L compared to the classical limit cannot be explained by the finite spatial extent of the quantum electronic orbitals alone [4] and is a non-trivial quantum effect. However the L^{-1} dependence of the energy-level spacing on system size is not altered by quantum effects; we believe that these numerical results convincingly establish that the HF DOS vanishes at the Fermi level in the thermodynamic limit [15].

For non-interacting electrons in the lowest Landau level states at the Fermi level are localized except (for typical disorder potentials) at $\nu = 1/2$. It is therefore surprising that our numerical results at $\nu = 1/5$ and $\nu = 1/2$ are not more different. For $\nu = 1/2$ the conductivity is finite [16] and the two-particle spectral response has a diffusive form at long distances [17]. To lowest order in interactions we can construct the HF self-energy from the non-interacting system eigenstates. Following work on interaction effects in disordered metals this leads [2] to a DOS change from the exchange self-energy

$$\frac{\delta D(E)}{D(E)} \sim \frac{-\partial \Sigma_X(E)}{\partial E} \sim \frac{e^2}{\hbar D} \int_{q_c} \frac{dq}{q^2} = \frac{e^2/\kappa \ell}{(\Gamma|E - \epsilon_F|)^{1/2}}. \quad (5)$$

Eq. (5) is a good agreement with our numerical results at $\nu = 1/2$ far enough from the Fermi energy where it is permissible to treat interactions in lowest order. In Eq. (5) we have evaluated the exchange self-energy using the bare two-dimensional $1/r$ interaction, $V(q) = 2\pi e^2/q$. It is the absence of screening in the HFA which makes the DOS change increase more strongly as energies approach ϵ_F than the $\ln(E)$ dependence expected for disordered metallic systems in two-dimensions. We expect that screening effects neglected in the HFA would increase the static dielectric constant, κ , and change our results quantitatively but not qualitatively for $\nu \neq 1/2$. For $\nu = 1/2$, however, the localization length diverges and κ may also diverge [18]. Further work will be required to determine whether $g_T(\epsilon)$ at $\nu \equiv 1/2$ is anomalous.

Finally we mention the downward shift in the chemical potential due to interactions which is visible in Fig. (1) and in Fig. (2). For the case of $\nu = 1/5$ the magnitude of this exchange self-energy shift in the chemical potential is much smaller than the value $\nu\sqrt{\pi/2}(e^2/\kappa\ell)$ calculated neglecting spatial correlations of the occupied orbitals and used in many considerations of the competition between disorder and weak interactions. This reduction has important implications for the compressibility of disordered electronic systems in a strong magnetic field and for the magnitude of exchange-enhanced spin-polarizations.

In conclusion we have performed finite system self-consistent HF calculations for a disordered system of two-dimensional quantum electrons in the strong magnetic field limit. We find that the HF energy-level spacing at the Fermi level varies as $e^2/\kappa L$, corresponding in the thermodynamic limit to a tunneling DOS per area which vanishes linearly as the Fermi energy is approached, for all filling factors. We expect that these results apply to systems with sufficient disorder that the fractional quantum Hall effect does not occur. This reduction in $g_T(\epsilon)$ near the Fermi energy results from static correlations in the self-consistent HF ground state which limit the phase space for adding an electron near the chemical potential. Similar reductions in $g_T(\epsilon)$ should occur for any correlated electron state, although the behavior of $g_T(\epsilon)$ at very low energies could differ qualitatively in the strongly correlated fluid states which occur in weak-disorder systems.

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REFERENCES

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- [1] B.L. Altschuler and A.G. Aronov, Solid State Commun. **39**, 115 (1979).
- [2] For reviews see Patrick A. Lee and T.V. Ramakrishnan, Rev. Mod. Phys. **57**, 287 (1985) and B.L. Altschuler, and A.G. Aronov in *Electron-Electron Interactions in Disordered Systems*, edited by A.L. Efros and M. Pollak (North-Holland, Amsterdam, 1985), p.1.
- [3] A.L. Efros and B.I. Shklovskii, J. Phys. C **8**, L49 (1975). For reviews see B.I. Shklovskii and A.L. Efros, *Electronic Properties of Doped Semiconductors* (Springer, Berlin, 1984) and A.L. Efros and B.I. Shklovskii in *Electron-Electron Interactions in Disordered Systems*, edited by A.L. Efros and M. Pollak (North-Holland, Amsterdam, 1985), p.409.
- [4] S.D. Baranovskii, A.L. Efros, B.L. Gelmont, and B.I. Shklovskii, J. Phys. C **12**, 1023 (1979); J.H. Davies, P.A. Lee, and T.M. Rice, Phys. Rev. B **29**, 4260 (1984); A. Möbius, M. Richter, and B. Dittler, Phys. Rev. B **45**, 11568 (1992).
- [5] S.M. Girvin, M. Jonson, and P.A. Lee, Phys. Rev. B **26**, 1651 (1982); A. Houghton, J.R. Senna, and S.C. Ying, Phys. Rev. B **25**, 6468 (1982).
- [6] H.P. Wei, S.Y. Lin, D.C. Tsui, and A.A.M. Pruisken, Phys. Rev. B **45**, 3926 (1992); H.P. Wei, D.C. Paalanen, and A.M.M. Pruisken, Phys. Rev. Lett. **61**, 1294 (1988); S. Koch, R.J. Haug, K. von Klitzing, and K.Ploog, Phys. Rev. B **46**, 1596 (1992); S. Koch, R.J. Haug, K. von Klitzing, and K.Ploog, Phys. Rev. B **43**, 6828 (1991).
- [7] D.G. Polyakov and B.I. Shklovskii, preprint (1993).
- [8] R.C. Ashoori, J.A. Lebens, N.P. Bigelow, and R.H. Silsbee, Phys. Rev. Lett. **64**, 681 (1990); *ibid*, preprint (1993).
- [9] J.P. Eisenstein, L.N. Pfeiffer, and K.W. West, Phys. Rev. Lett. **69**, 3804 (1992). The samples used in these experiments may have insufficient disorder for our calculations to

apply.

- [10] See for example, D. Yoshioka, B.I. Halperin, and P.A. Lee, Phys. Rev. Lett. **50**, 1219 (1983).
- [11] A.H. MacDonald and G.C. Aers, Phys. Rev. B **34**, 2906 (1986).
- [12] A.H. MacDonald and S.M. Girvin, Phys. Rev. **B 38**, 6295 (1988).
- [13] E. Brézin, David J. Gross, and C. Itzykson, Nuclear Physics **B235**, 24 (1984); Franz Wegner, Z. Phys. B, **51**, 279 (1983).
- [14] See for example Tsuneya Ando, J. Phys. Soc. Jpn. **52**, 1740 (1983).
- [15] Further work aimed at studying quantitatively the dependence on filling factor and its relation to the diverging localization length at the Landau level center is in progress.
- [16] See for example Y. Huo, R.E. Hetzel, and R.N. Bhatt, Phys. Rev. Lett. **70**, 481 (1993) and references therein.
- [17] J.T. Chalker and G.J. Daniell, Phys. Rev. Lett. **61**, 593 (1988).
- [18] S.-R. Eric Yang, A.H. MacDonald, and B.I. Shklovskii, work in progress.

FIGURES

FIG. 1. Tunneling density-of-states histograms obtained from self-consistent Hartree-Fock calculations at $\nu = 1/5$. $D_{\Delta E}(E)$ is the number of Hartree-Fock eigenvalues at energies between E and $E + \Delta E$ including all disorder realizations. These results are for $N_\phi = 245$ and $N_D = 90$ disorder realizations. For these plots $\Delta E = 0.028\Gamma$.

FIG. 2. Tunneling density-of-states histograms for $\nu = 1/2$, $N_\phi = 288$, $N_D = 60$, and $\Delta E = 0.028\Gamma$.

FIG. 3. Finite system density-of-states minima versus x . At a given filling factor results at different values of γ and different system sizes collapse onto a single curve. $D_{\Delta E}(E_F)\Gamma/\Delta EN_\phi N_D$ is the density of states per flux quantum per Γ energy interval. The horizontal arrows at the right hand side of the figure indicate the exact values for the large x (no interaction), large-system limit. The plotting symbols are horizontal bars ($\gamma = 0.1$), crosses ($\gamma = 0.2$), diamonds ($\gamma = 0.3$), squares ($\gamma = 0.4$), and octagons ($\gamma = 0.5$). The solid lines are guides to the eye. For $\nu = 1/2$ the plotted (N_ϕ, N_D) are (128,90), (288,60), and (450,7). For $\nu = 1/5$ they are (80,150), (125,120), and (245,90). ($x = \gamma^{-1}(2\pi/N_\phi)^{1/2}$.) The dashed line is the Efros-Shklovskii expression for classical electrons.